

Product Standards

Part No.	AN44075A
Package Code No.	HSOP034-P-0300A

Semiconductor Company
Matsushita Electric Industrial Co., Ltd.

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AN44075A

Driver IC for DC Motor

■ Overview

AN44075A is a one channel H-bridge driver IC. 1-ch. DC motor can be controlled by a single driver IC.

■ Features

- Built-in thermal protection and low voltage detection circuit
- Built-in over current protection (when external resistance is added to Pin 7 and Pin 8.)
- Built-in 5 V power supply

■ Applications

- IC for DC motor drives

■ Package

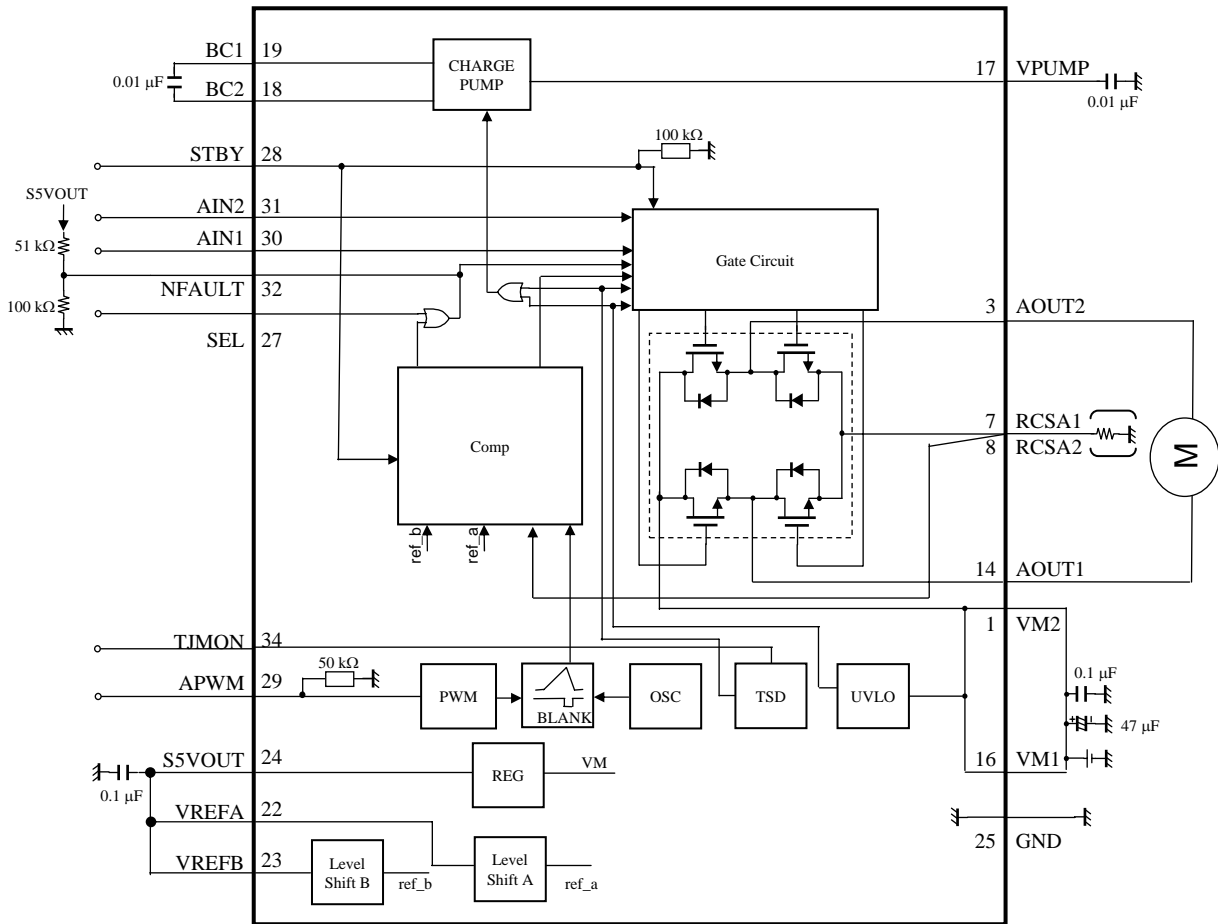
- 34 pin Plastic Small Outline Package with Back Heat Sink (SOP Type)

■ Type

- Bi-CDMOS IC

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■ Application Circuit Example

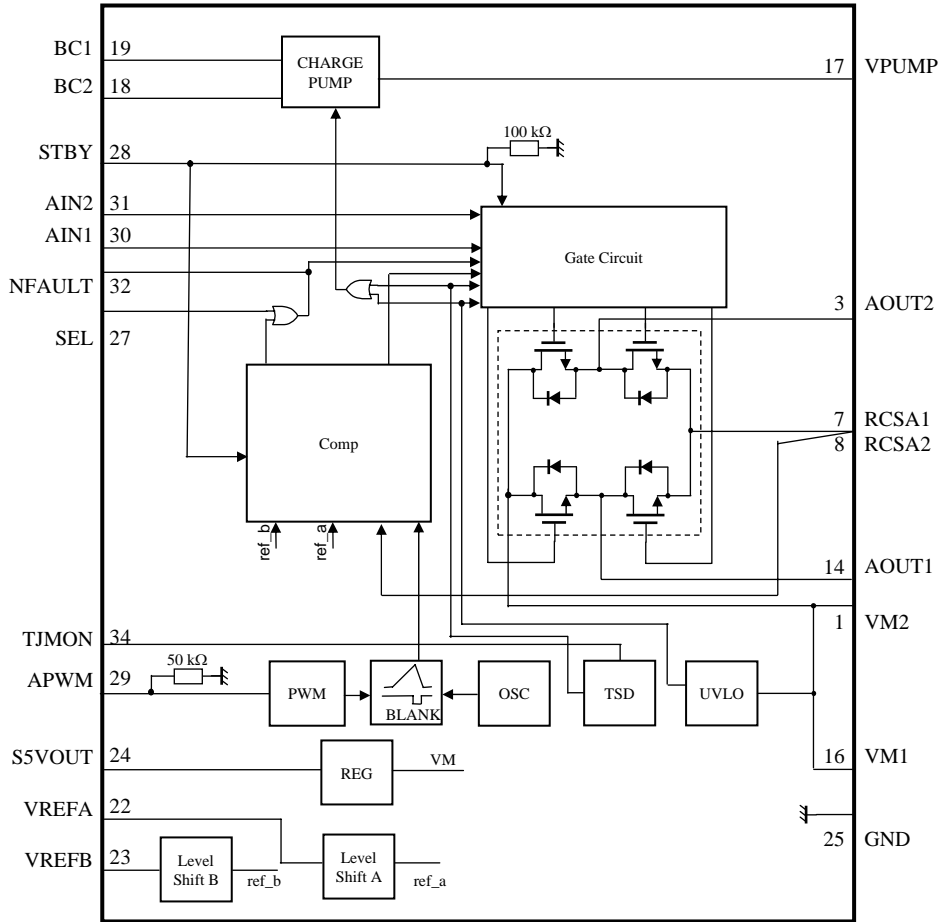


Note) • This application circuit is shown as an example but does not guarantee the design for mass production set.

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■ Block Diagram



Note) This block diagram is for explaining functions. The part of the block diagram may be omitted, or it may be simplified.

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■ Pin Descriptions

Pin No.	Pin name	Type	Description
1	VM2	Power supply	Motor power supply 2
2	N.C.	—	not used
3	AOUT2	Output	Motor drive output 2
4	N.C.	—	not used
5	N.C.	—	not used
6	N.C.	—	not used
7	RCSA1	Input / Output	Current detection 1
8	RCSA2	Input / Output	Current detection 2
9	GND	Ground	Die pad ground
10	N.C.	—	not used
11	N.C.	—	not used
12	N.C.	—	not used
13	N.C.	—	not used
14	AOUT1	Output	Motor drive output 1
15	N.C.	—	not used
16	VM1	Power supply	Motor power supply 1
17	VPUMP	Output	Charge Pump circuit output
18	BC2	Output	Charge Pump capacitor connection 2
19	BC1	Output	Charge Pump capacitor connection 1
20	N.C.	—	not used
21	N.C.	—	not used
22	VREFA	Input	Peak current setting input
23	VREFB	Input	Load short threshold input
24	S5VOUT	Output	Internal reference voltage (5 V output)
25	GND	Ground	Signal ground
26	GND	Ground	Die pad ground
27	SEL	Input	Test mode input
28	STBY	Input	Standby input
29	APWM	Input	PWM input
30	AIN1	Input	Forward-Reverse input
31	AIN2	Input	Brake mode input
32	NFAULT	Output	Abnormal detection output
33	N.C.	—	not used
34	TJMON	Output	VBE monitor

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■ Absolute Maximum Ratings

Note) Absolute maximum ratings are limit values which are not destructed, and are not the values to which operation is guaranteed.

A No.	Parameter	Symbol	Rating	Unit	Note
1	Supply voltage1 (Pin 1, Pin 16)	V_M	37	V	*1
2	Power dissipation	P_D	0.466	W	*2
3	Operating ambient temperature	T_{opr}	-20 to +70	°C	*3
4	Storage temperature	T_{stg}	-55 to +150	°C	*3
5	Output pin voltage (Pin 3, Pin 14)	V_{OUT}	37	V	*4
6	Motor drive current (Pin 3, Pin 14)	I_{OUT}	±3.0	A	*4, *5
7	Flywheel diode current (Pin 3, Pin 14)	I_f	3.0	A	*4, *5

Notes) *1 : The values under the condition not exceeding the above absolute maximum ratings and the power dissipation.

*2 : The power dissipation shown is the value at $T_a = 70^\circ\text{C}$ for the independent (unmounted) IC package without a heat sink.

When using this IC, refer to the P_D - T_a diagram of the package standard and design the heat radiation with sufficient margin so that the allowable value might not be exceeded based on the conditions of power supply voltage, load, and ambient temperature.

*3 : Except for the power dissipation, operating ambient temperature, and storage temperature, all ratings are for $T_a = 25^\circ\text{C}$.

*4 : Do not apply current or voltage from outside to any pin not listed above.

In the circuit current, (+) means the current flowing into IC and (-) means the current flowing out of IC.

*5 : It is the rating value when connecting the heat sink on the rear face of the package to the ground pattern on the glass epoxy 4-layered PCB. (the ground area in the second and third layer : more than 1 500 mm²)

■ Operating Supply Voltage Range

Parameter	Symbol	Range	Unit	Note
Operating supply voltage range	V_M	10.0 to 35.0	V	*

Note) * : The values under the condition not exceeding the above absolute maximum ratings and the power dissipation.

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■ Allowed Voltage and Current Ranges

Notes) • Rating Voltage is voltage of pin on GND

- Do not apply current or voltage from outside to any pin not listed below.

Pin No.	Pin name	Rating	Unit	Note
7	RCSA1	+2.5	V	—
8	RCSA2	+2.5	V	—
17	VPUMP	$(V_M - 2)$ to 43	V	—
18	BC2	$(V_M - 1)$ to 43	V	—
19	BC1	$V_M + 0.3$	V	—
22	VREFA	-0.3 to 6	V	—
23	VREFB	-0.3 to 6	V	—
24	S5VOUT	-7 to 0	mA	*1
27	SEL	-0.3 to 6	V	—
28	STBY	-0.3 to 6	V	—
29	APWM	-0.3 to 6	V	—
30	AIN1	-0.3 to 6	V	—
31	AIN2	-0.3 to 6	V	—
32	NFAULT	-0.3 to 6	V	—
32	NFAULT	4	mA	—

Note) *1 : It is the rating when using with the rang of $V_M = 16\text{ V}$ to 35 V . When $V_M = 10\text{ V}$ to 15 V , the rating is -4 mA .

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■ Electrical Characteristics at $V_M = 24\text{ V}$

Note) $T_a = 25^\circ\text{C} \pm 2^\circ\text{C}$ unless otherwise specified.

B No.	Parameter	Symbol	Test circuits	Conditions	Limits			Unit	Note
					Min	Typ	Max		
Output drivers									
1	High-level output saturation voltage	V_{OH}	1	$I_{SA1} = I_{SA2} = -1\text{ A}$	V_M -0.47	V_M -0.36	—	V	—
2	Low-level output saturation voltage	V_{OL}	1	$I_{SA1} = I_{SA2} = 1\text{ A}$	—	0.50	0.65	V	—
3	Flywheel diode forward voltage	V_{DI}	2	$I_{DI} = \pm 1\text{ A}$	0.5	1.0	1.5	V	—
4	Output leakage current	I_{LEAK}	1	$V_M = 37\text{ V}, V_{SRCS} = 0\text{ V}$	—	10	20	μA	—
Power supply									
5	Supply current 1 (Sleep)	I_{M1}	1	$V_{STBY} = 0\text{ V}$	—	65	105	μA	—
6	Supply current 2 (with circuit turned on)	I_{M2}	1	$V_{STBY} = 5\text{ V}$	—	7.3	12	mA	—
7	Reference voltage	V_{SSVOUT}	1	$I_{SSVOUT} = -2.5\text{ mA}$	4.5	5.0	5.5	V	—
8	Output impedance	Z_{SSVOUT}	1	$\Delta I_{SSVOUT} = -5\text{ mA}$	—	18	27	Ω	—
IN input									
9	High-level IN input voltage	V_{INH}	1	—	2.1	—	5	V	—
10	Low-level IN input voltage	V_{INL}	1	—	0	—	0.6	V	—
11	High-level IN input current	I_{INH}	1	$V_{AIN1} = V_{AIN2} = 5\text{ V}$	-10	—	10	μA	—
12	Low-level IN input current	I_{INL}	1	$V_{AIN1} = V_{AIN2} = 0\text{ V}$	-10	—	10	μA	—
Standby input									
13	High-level STBY input voltage	V_{STBYH}	1	—	2.1	—	5	V	—
14	Low-level STBY input voltage	V_{STBYL}	1	—	0	—	0.6	V	—
15	High-level STBY input current	I_{STBYH}	1	$V_{STBY} = 5\text{ V}$	30	—	80	μA	—
16	Low-level STBY input current	I_{STBYL}	1	$V_{STBY} = 0\text{ V}$	-10	—	10	μA	—
PWM input									
17	High-level PWM input voltage	V_{PWMH}	1	—	2.1	—	5	V	—
18	Low-level PWM input voltage	V_{PWML}	1	—	0	—	0.6	V	—
19	High-level PWM input current	I_{PWMH}	1	$V_{APWM} = 5\text{ V}$	60	—	150	μA	—
20	Low-level PWM input current	I_{PWML}	1	$V_{APWM} = 0\text{ V}$	-10	—	10	μA	—
21	PWM Input Max frequency	f_{PWM}	1	—	—	—	200	kHz	—
22	Input Min pulse width	t_w	1	—	2	—	—	μs	—

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■ Electrical Characteristics (continued) at $V_M = 24\text{ V}$

Note) $T_a = 25^\circ\text{C} \pm 2^\circ\text{C}$ unless otherwise specified.

B No.	Parameter	Symbol	Test circuits	Conditions	Limits			Unit	Note
					Min	Typ	Max		
Peak current detection / Over current protection									
23	Input bias current	I_{REF}	1	$V_{REFA} = V_{REFB} = 5\text{ V}$	83	100	125	μA	—
24	PWM frequency	f_{PWM}	1	$V_{REFA} = 0\text{ V}, V_{REFB} = 5\text{ V}$	17	26	35	kHz	—
25	Pulse blanking time	T_B	1	$V_{REFA} = 0\text{ V}, V_{REFB} = 5\text{ V}$	1.5	2.5	4.5	μs	—
26	Comp threshold 1	V_{TH1}	1	$V_{REFA} = V_{REFB} = 5\text{ V}$	480	500	520	mV	—
27	Comp threshold 2	V_{TH2}	1	$V_{REFA} = 5.5\text{ V}, V_{REFB} = 2.5\text{ V}$	475	500	525	mV	—
28	NFAULT output voltage	V_{NFLT}	1	$I_{NFLT} = 1\text{ mA}$	—	—	0.4	V	—

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■ **Electrical Characteristics (Reference values for design) at $V_M = 24\text{ V}$**

Notes) $T_a = 25^\circ\text{C} \pm 2^\circ\text{C}$ unless otherwise specified.

The characteristics listed below are reference values derived from the design of the IC and are not guaranteed by inspection.

If a problem does occur related to these characteristics, we will respond in good faith to user concerns.

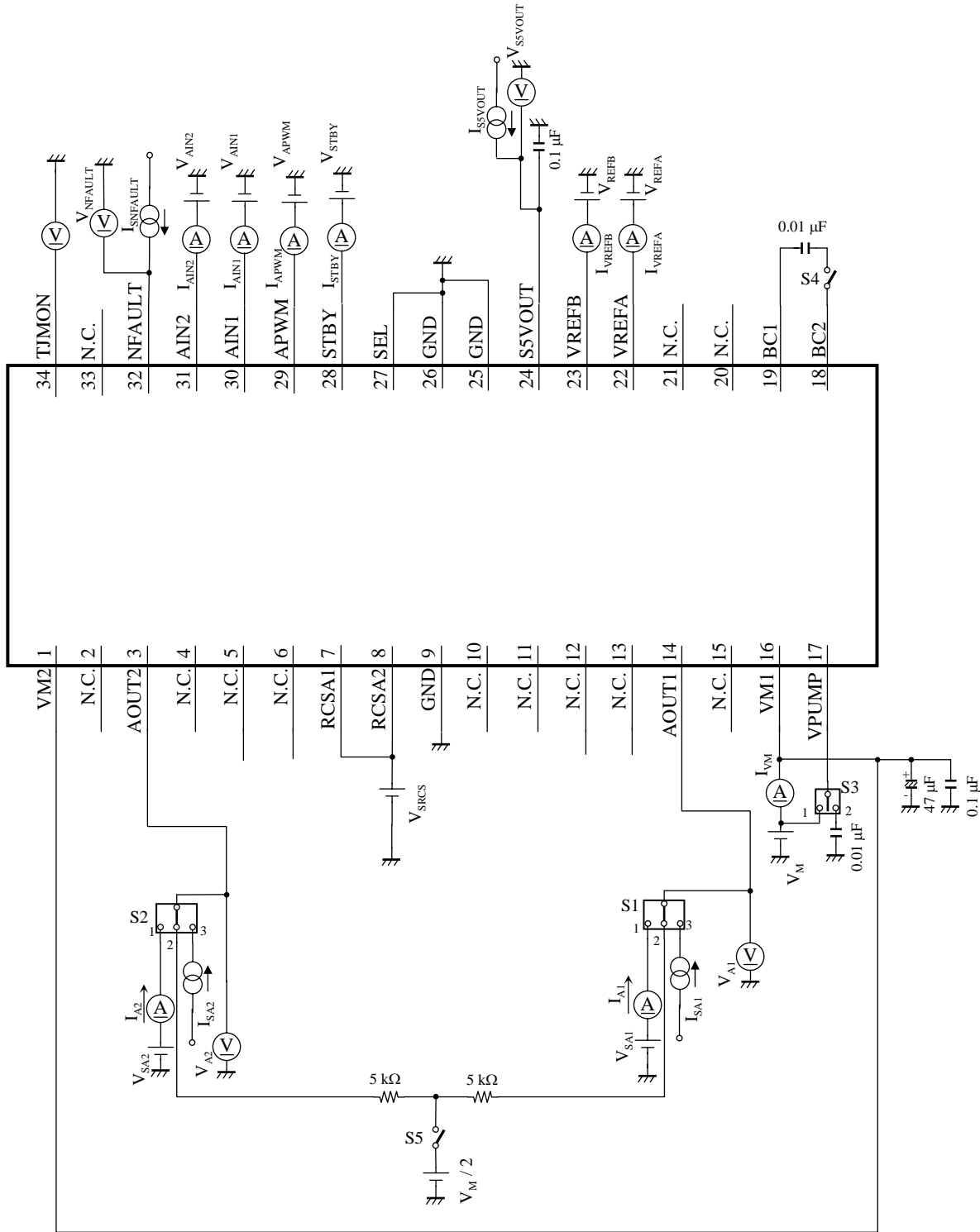
B No.	Parameter	Symbol	Test circuits	Conditions	Reference values			Unit	Note
					Min	Typ	Max		
Output drivers									
29	Output slew rate 1	VT_r	—	Rising edge	—	270	—	V/ μs	—
30	Output slew rate 2	VT_f	—	Falling edge	—	330	—	V/ μs	—
31	Dead time	T_D	—	—	—	0.45	—	μs	—
Thermal protection									
32	Thermal protection operating temperature	TSD_{on}	—	—	—	150	—	$^\circ\text{C}$	—
33	Thermal protection hysteresis width	ΔTSD	—	—	—	40	—	$^\circ\text{C}$	—
Low voltage protection									
34	Protection operating voltage	UVLO1	—	—	—	8.0	—	V	—
35	Protection release voltage	UVLO2	—	—	—	8.6	—	V	—

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■ Test Circuit Diagram

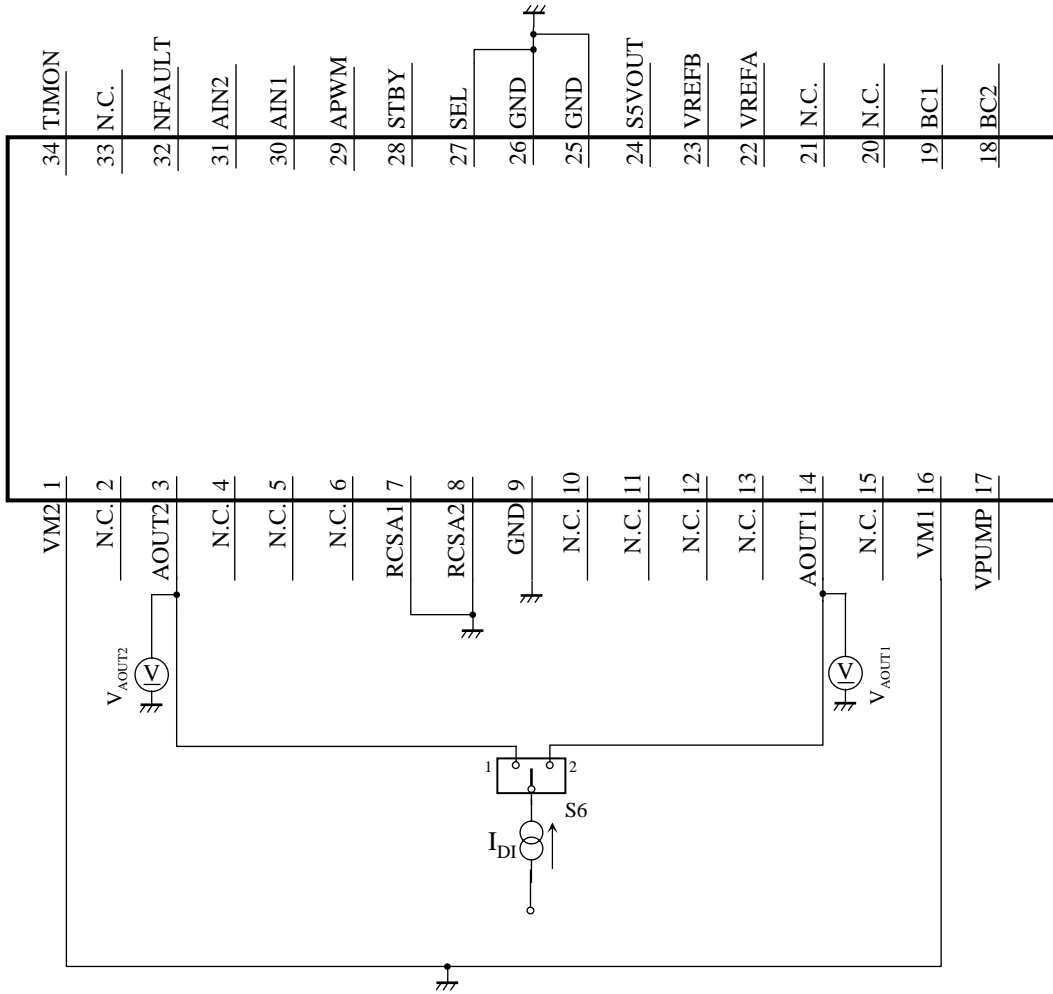
1. Test Circuit Diagram1



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■ Test Circuit Diagram (continued)

2. Test Circuit Diagram2



C No.	Measuring Pin	Relay Conditions	Voltage Conditions
		S6	I_{D1}
3	3	1	1 A
			-1 A
	14	2	1 A
			-1 A

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■ Electrical Characteristics Test Procedures

1. Test Circuit 1

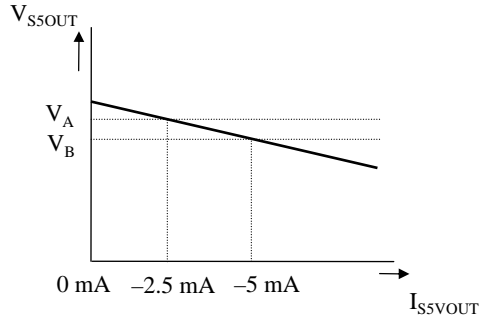
C No.	Measuring Pin	Relay Conditions				Voltage Conditions													
		S1 S2	S3	S4	S5	V _{STBY}	V _{APWM}	V _{AIN1}	V _{AIN2}	V _{REFA}	V _{REFB}	V _{SRCS}	V _{SA1} V _{SA2}	V _M	I _{SA1}	I _{SA2}	I _{FAULT}	I _{SSVOUT}	
1 2	3, 14	3	2	on	off	5 V	5 V	5 V	5 V	5 V	5 V	0 V	Hi-Z	24 V	-1.0 A	1.0 A	Hi-Z	Hi-Z	
		3	2	on	off	5 V	5 V	0 V	5 V	5 V	5 V	0 V	Hi-Z	24 V	1.0 A	-1.0 A	Hi-Z	Hi-Z	
4	3, 14	1	1	off	off	5 V	0 V	5 V	5 V	5 V	5 V	0 V	37 V	37 V	Hi-Z	Hi-Z	Hi-Z	Hi-Z	
		1	1	off	off	5 V	0 V	5 V	0 V	5 V	5 V	0 V	0 V	37 V	Hi-Z	Hi-Z	Hi-Z	Hi-Z	
5	1, 16	3	2	on	off	0 V	5 V	5 V	0 V	5 V	5 V	0 V	Hi-Z	24 V	Hi-Z	Hi-Z	Hi-Z	Hi-Z	
6	1, 16	3	2	on	off	5 V	5 V	5 V	0 V	5 V	5 V	0 V	Hi-Z	24 V	Hi-Z	Hi-Z	Hi-Z	Hi-Z	
7	24	3	2	on	off	5 V	5 V	5 V	0 V	5 V	5 V	0 V	Hi-Z	24 V	Hi-Z	Hi-Z	Hi-Z	-2.5 mA	
8	24	3	2	on	off	5 V	5 V	5 V	0 V	5 V	5 V	0 V	Hi-Z	24 V	Hi-Z	Hi-Z	Hi-Z	-5 mA	
9 17	3, 14	2	2	on	off	5 V	2.1 V	2.1 V	2.1 V	5 V	5 V	0 V	Hi-Z	24 V	Hi-Z	Hi-Z	Hi-Z	Hi-Z	
10 17	3, 14	2	2	on	off	5 V	2.1 V	0.6 V	2.1 V	5 V	5 V	0 V	Hi-Z	24 V	Hi-Z	Hi-Z	Hi-Z	Hi-Z	
9 18	3, 14	2	2	on	off	5 V	0.6 V	0.6 V	2.1 V	5 V	5 V	0 V	Hi-Z	24 V	Hi-Z	Hi-Z	Hi-Z	Hi-Z	
10 18	3, 14	2	2	on	off	5 V	0.6 V	0.6 V	0.6 V	5 V	5 V	0 V	Hi-Z	24 V	Hi-Z	Hi-Z	Hi-Z	Hi-Z	
11 15 19	28, 29, 30, 31	3	2	on	off	5 V	5 V	5 V	5 V	5 V	5 V	0 V	Hi-Z	24 V	Hi-Z	Hi-Z	Hi-Z	Hi-Z	
12	29, 30, 31	3	2	on	off	5 V	0 V	0 V	0 V	5 V	5 V	0 V	Hi-Z	24 V	Hi-Z	Hi-Z	Hi-Z	Hi-Z	
13	3, 14	2	2	on	off	2.1 V	5 V	5 V	5 V	5 V	5 V	0 V	Hi-Z	24 V	Hi-Z	Hi-Z	Hi-Z	Hi-Z	
14	3, 14	2	2	on	off	0.6 V	5 V	5 V	5 V	5 V	5 V	0 V	Hi-Z	24 V	Hi-Z	Hi-Z	Hi-Z	Hi-Z	
16	28	3	2	on	off	0 V	0 V	0 V	0 V	5 V	5 V	0 V	Hi-Z	24 V	Hi-Z	Hi-Z	Hi-Z	Hi-Z	
21	3	2	2	on	off	5 V	Pulse	5 V	5 V	5 V	5 V	0 V	Hi-Z	24 V	Hi-Z	Hi-Z	Hi-Z	Hi-Z	
22	3	2	2	on	off	5 V	Pulse	5 V	5 V	5 V	5 V	0 V	Hi-Z	24 V	Hi-Z	Hi-Z	Hi-Z	Hi-Z	
23	22, 23	3	2	on	off	5 V	5 V	5 V	5 V	5 V	5 V	0 V	Hi-Z	24 V	Hi-Z	Hi-Z	Hi-Z	Hi-Z	
24	3	2	2	on	on	5 V	5 V	5 V	5 V	0 V	5 V	1 V	Hi-Z	24 V	Hi-Z	Hi-Z	Hi-Z	Hi-Z	
25	3	2	2	on	on	5 V	5 V	5 V	5 V	0 V	5 V	1 V	Hi-Z	24 V	Hi-Z	Hi-Z	Hi-Z	Hi-Z	
26	3	2	2	on	off	5 V	5 V	5 V	5 V	5 V	5 V	Sweep	Hi-Z	24 V	Hi-Z	Hi-Z	Hi-Z	Hi-Z	
27	14	2	2	on	off	5 V	5 V	5 V	5 V	5.5 V	2.5 V	Sweep	Hi-Z	24 V	Hi-Z	Hi-Z	Hi-Z	Hi-Z	
28	32	2	2	on	off	5 V	5 V	5 V	5 V	5 V	0 V	1 V	Hi-Z	24 V	Hi-Z	Hi-Z	1 mA	Hi-Z	

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■ Electrical Characteristics Test Procedures (continued)

1. Test Circuit 1 (continued)

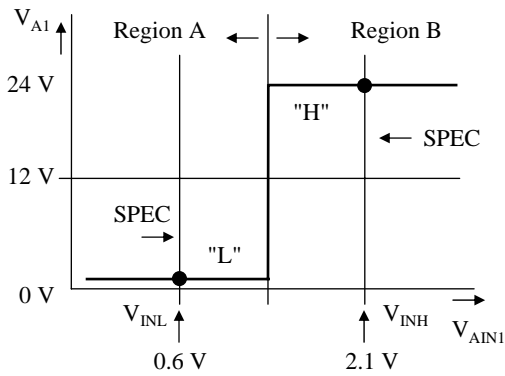
8) Output impedance Z_{SSVOUT}



$$Z_{SSVOUT} = \frac{V_A - V_B}{2.5 \text{ mA}}$$

9) High-level IN input voltage V_{INH}

10) Low-level IN input voltage V_{INL}



Check the conditions by measuring the AOUT1 voltage, AOUT2 voltage with the input voltage set to high level and low level respectively.

Region A : The Power transistor on the flow-in side turned on.
Another Power transistor on the flow-out side turned off.

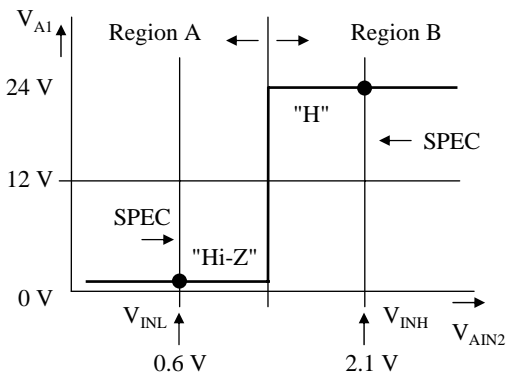
Region B : The Power transistor on the flow-in side turned off.
Another Power transistor on the flow-out side turned on.

Measuring Pin	Voltage Conditions		Status
	V_{AIN1}	V_{AIN2}	
V_{AOUT1}	2.1 V	2.1 V	"H" output
	0.6 V	2.1 V	"L" output
V_{AOUT2}	2.1 V	2.1 V	"L" output
	0.6 V	2.1 V	"H" output

Check the conditions by measuring the AOUT1 voltage, AOUT2 voltage with the input voltage set to high level and low level respectively.

Region A : The Power transistor on the flow-in side turned off.
Another Power transistor on the flow-out side turned off.

Region B : The Power transistor on the flow-in side turned off.
Another Power transistor on the flow-out side turned on.



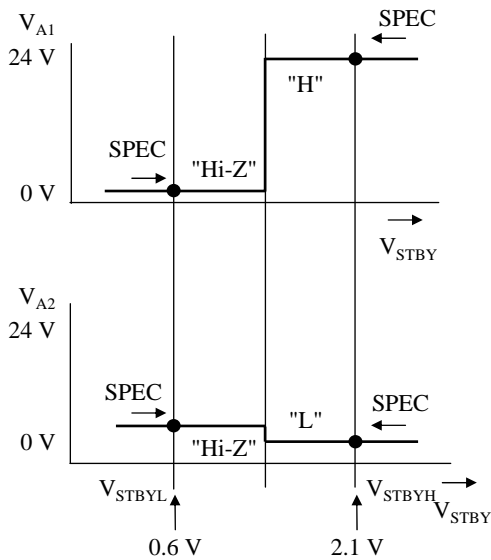
Measuring Pin	Voltage Conditions		Status
	V_{AIN1}	V_{AIN2}	
V_{AOUT1}	0.6 V	2.1 V	"H" output
	0.6 V	0.6 V	"Hi-Z" output
V_{AOUT2}	0.6 V	2.1 V	"H" output
	0.6 V	0.6 V	"Hi-Z" output

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■ Electrical Characteristics Test Procedures (continued)

1. Test Circuit 1 (continued)

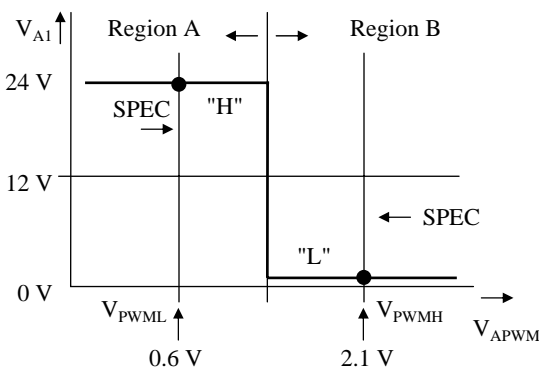
- 13) High-level STBY input voltage V_{STBYH}
- 14) Low-level STBY input voltage V_{STBYL}



Check the conditions by measuring the AOUT1 voltage, AOUT2 voltage with the input voltage set to high level and low level respectively.

Measuring Pin	Voltage Conditions	Status
	V_{STBY}	
V_{AOUT1}	0.6 V	"Hi-Z" output
V_{AOUT2}	0.6 V	"Hi-Z" output
V_{AOUT1}	2.1 V	"H" output
V_{AOUT2}	2.1 V	"L" output

- 17) High-level PWM input voltage V_{PWMLH}
- 18) Low-level PWM input voltage V_{PWMLL}



Check the conditions by measuring the AOUT1 voltage with the input voltage set to high level and low level respectively.

Measuring Pin	Voltage Conditions	Status
	V_{APWM}	
V_{AOUT1}	0.6 V	"H" output
	2.1 V	"L" output

Region A : The Power transistor on the flow-in side turned off.
Another Power transistor on the flow-out side turned on.

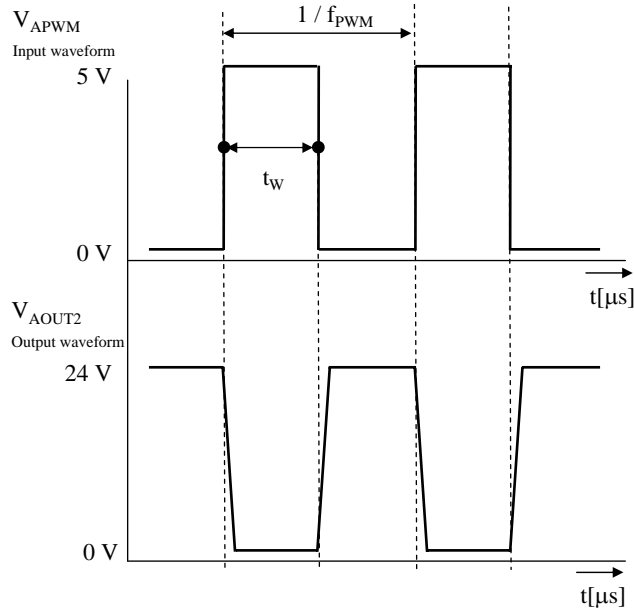
Region B : The Power transistor on the flow-in side turned on.
Another Power transistor on the flow-out side turned off.

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■ Electrical Characteristics Test Procedures (continued)

1. Test Circuit 1 (continued)

- 21) PWM Input Max frequency f_{PWM}
- 22) Input Min pulse width t_w



$V_{APWM} = \text{Pulse}$

Check the conditions by measuring the AOUT2 voltage waveform.

PWM Input Pulse

	Pulse Conditions	Input waveform
	V_{APWM}	
Frequency	200 kHz	Square-wave pulse
Duty	40%	
Amplitude	5 V[p-p]	
Offset	2.5 V	

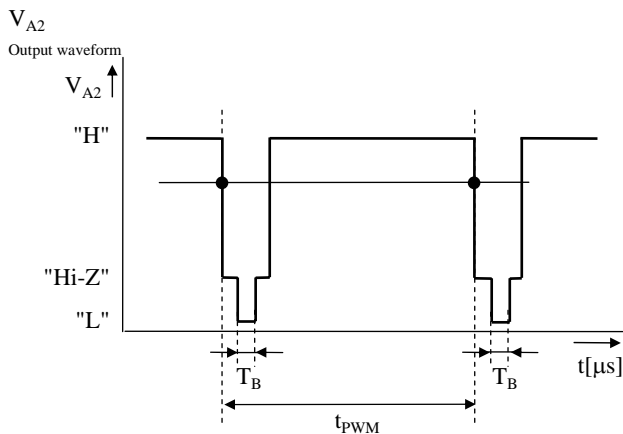
PWM Input Max Frequency f_{PWM}

Check the conditions by measuring the cycle time of output voltage pulses.

Input Min pulse width t_w

Check the conditions by measuring the Duty of output voltage pulses.

- 24) PWM frequency 1 f_{PWM}
- 25) Pulse blanking time T_B



The value is obtained from V_{A2} voltage at $V_{REFA} = 0\text{ V}$, $V_{REFB} = 5\text{ V}$, $A_{IN1} = 5\text{ V}$.

The V_{A2} output waveform is shown below.

PWM Frequency f_{PWM}

Measure the cycle time of output voltage pulses and obtain the value from the following formula.

$$f_{PWM} = \frac{1}{t_{PWM}}$$

Pulse blanking time T_B

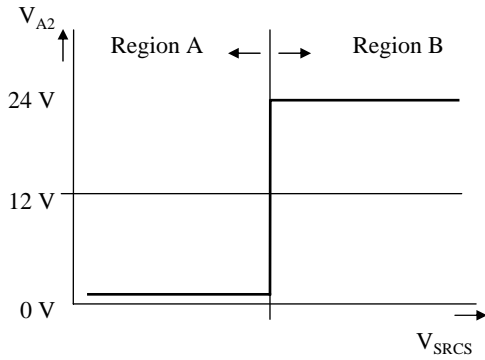
Measure the time of V_{A2} output voltage low level.

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■ Electrical Characteristics Test Procedures (continued)

1. Test Circuit 1 (continued)

26) Comp threshold 1 V_{TH1}



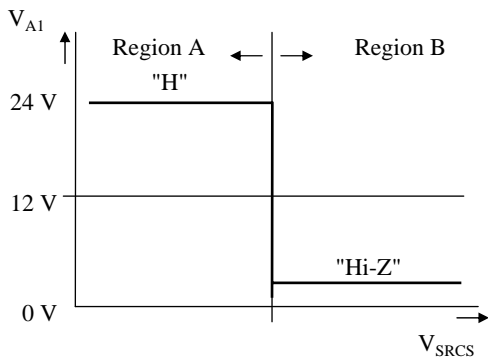
Make RCS voltage sweep
and measure threshold voltage of output pins.

Region A : Always output "L"
Region B : Min. duty, output "L"



27) Comp threshold 2

V_{TH2}



Make RCS voltage sweep
and measure threshold voltage of output pins.

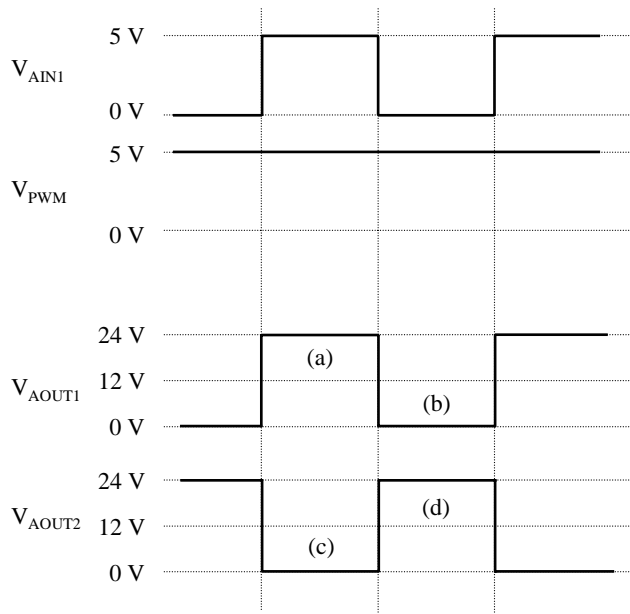
Region A : Always output "H"
Region B : Output "Hi-Z"

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■ Electrical Characteristics Test Procedures (continued)

1. Test Circuit 1 (continued)

- 1) High-level output saturation voltage V_{OH}
- 2) Low-level output saturation voltage V_{OL}



C No.	Measuring Pin	Current Conditions	Status
		I_{SA1}, I_{SA2}	
1	AOUT1 / AOUT2	-1.0 A	Measure each voltage of the AOUT1 and AOUT2 at (a) , (d) above
2	AOUT1 / AOUT2	1.0 A	Measure each voltage of the AOUT1 and AOUT2 at (c) , (b) above

2. Test Circuit 2

- 3) Flywheel diode forward voltage V_{DI}

C No.	Measuring Pin	Relay Conditions
		S6
3	AOUT1 / AOUT2	Measure the diode voltage at each level on contacts1, 2 of S6.

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■ Technical Data

- Circuit diagrams of the input/output part and pin function descriptions

Note) The characteristics listed below are reference values based on the IC design and are not guaranteed.

Pin No.	Waveform and voltage	Inner circuit	Impedance	Description
3 7 8 14				Pin 7 : Current detection 1 8 : Current detection 2 3 : Motor drive output 2 14 : Motor drive output 1
17 18				Pin 18 : Charge Pump capacitor 2 17 : Charge Pump circuit output

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■ Technical Data (continued)

- Circuit diagrams of the input/output part and pin function descriptions (continued)

Note) The characteristics listed below are reference values based on the IC design and are not guaranteed.

Pin No.	Waveform and voltage	Inner circuit	Impedance	Description
19				Pin 19 : Charge Pump capacitor 1
22			50 kΩ	Pin 22 : Peak current setting input

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■ Technical Data (continued)

- Circuit diagrams of the input/output part and pin function descriptions (continued)

Note) The characteristics listed below are reference values based on the IC design and are not guaranteed.

Pin No.	Waveform and voltage	Inner circuit	Impedance	Description
23		<p>Pin23 VREFB</p> <p>40k</p> <p>10k</p>	50 kΩ	Pin 23 : Load short threshold input
24		<p>2k</p> <p>102k</p> <p>Pin24 S5VOUT</p>		Pin 24 : Internal reference voltage (5 V output)

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■ Technical Data (continued)

- Circuit diagrams of the input/output part and pin function descriptions (continued)

Note) The characteristics listed below are reference values based on the IC design and are not guaranteed.

Pin No.	Waveform and voltage	Inner circuit	Impedance	Description
28		<p style="text-align: center;">Pin28 STBY ②8</p>	100 kΩ	Pin 28 : Standby input
27 29		<p style="text-align: center;">Pin27 SEL 29 APWM</p>	54 kΩ	Pin 27 : Test mode input 29 : PWM input

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■ Technical Data (continued)

- Circuit diagrams of the input/output part and pin function descriptions (continued)

Note) The characteristics listed below are reference values based on the IC design and are not guaranteed.

Pin No.	Waveform and voltage	Inner circuit	Impedance	Description
30 31				Pin 30 : Forward / Reverse input 31 : Brake mode input
32				Pin 32 : Abnormal detection output

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■ Technical Data (continued)

- Circuit diagrams of the input/output part and pin function descriptions (continued)

Note) The characteristics listed below are reference values based on the IC design and are not guaranteed.

Pin No.	Waveform and voltage	Inner circuit	Impedance	Description
34				Pin 34 : VBE monitor
Sym bols				

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- Technical Data (continued)
 - Control mode (truth table)

INPUT				OUTPUT		
STBY	AIN1	AIN2	APWM	AOUT1	AOUT2	Mode
"H"	—	"H"	"L"	"H"	"H"	Short Brake
	"L"	—	"H"	"L"	"H"	Forward
	"H"	—	"H"	"H"	"L"	Reverse
	—	"L"	"L"	OFF	OFF	Stop
"L"	—	—	—	OFF	OFF	Standby

INPUT	OUTPUT
SEL	Mode
"H"	Short Detect off
"L"	Short Detect on

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■ Usage Notes

• Special attention and precaution in using

1. This IC is intended to be used for general electronic equipment [DC motor with brass].
Consult our sales staff in advance for information on the following applications:
 - Special applications in which exceptional quality and reliability are required, or if the failure or malfunction of this IC may directly jeopardize life or harm the human body.
 - Any applications other than the standard applications intended.
 - (1) Space appliance (such as artificial satellite, and rocket)
 - (2) Traffic control equipment (such as for automobile, airplane, train, and ship)
 - (3) Medical equipment for life support
 - (4) Submarine transponder
 - (5) Control equipment for power plant
 - (6) Disaster prevention and security device
 - (7) Weapon
 - (8) Others : Applications of which reliability equivalent to (1) to (7) is required
2. Pay attention to the direction of LSI. When mounting it in the wrong direction onto the PCB (printed-circuit-board), it might smoke or ignite.
3. Pay attention in the PCB (printed-circuit-board) pattern layout in order to prevent damage due to short circuit between pins. In addition, refer to the Pin Description for the pin configuration.
4. Perform a visual inspection on the PCB before applying power, otherwise damage might happen due to problems such as a solder-bridge between the pins of the semiconductor device. Also, perform a full technical verification on the assembly quality, because the same damage possibly can happen due to conductive substances, such as solder ball, that adhere to the LSI during transportation.
5. Take notice in the use of this product that it might break or occasionally smoke when an abnormal state occurs such as output pin- V_M short (Power supply fault), output pin-GND short (Ground fault), output-to-output-pin short (load short) or the leakage between pins.
Pay special attention to the following pins so that are not short-circuited with the V_M pin, ground pin, other output pins or RCS pin.
 - (1) AOUT1 (Pin 14), AOUT2 (Pin 3)
 - (2) BC1 (Pin 19), BC2 (Pin 18), VPUMP (Pin 17)
 - (3) VM1 (Pin 16), VM2 (Pin 1), S5VOUT (Pin 24)
 - (4) RCSA1 (Pin 7), RCSA2 (Pin 8)
 And, safety measures such as an installation of fuses are recommended because the extent of the above-mentioned damage and smoke emission will depend on the current capability of the power supply.
6. When using the LSI for new models, verify the safety including the long-term reliability for each product.
7. When the application system is designed by using this LSI, be sure to confirm notes in this book.
Be sure to read the notes to descriptions and the usage notes in the book.
8. Please connect the metallic plate (fin) on the back side of the IC with the GND potential (the pattern for cooling).
9. The protection circuit is for maintaining safety against abnormal operation. Therefore, the protection circuit should not work during normal operation.
Especially the thermal protection circuit might be damaged before it could operate if the area of safety operation of the device or the absolute maximum rating is instantaneously exceeded due to the output pin to V_M short (Power supply fault), or output pin to GND short (Ground fault) .
10. Unless specified in the product specifications, make sure the negative voltage or excessive voltage are not applied to the pins because the device might be damaged, which could happen due to negative voltage or excessive voltage generated during the ON and OFF timing when the inductive load of a motor coil, optical pick-up or transformer is being driven.
11. The product which has specified ASO (Area of Safe Operation) should be operated in ASO.
12. Check the risk that is caused by the failure of external components.

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■ Usage Notes (continued)

13. Perform thermal design work with consideration of a sufficient margin to keep the power dissipation based on supply voltage, load, and ambient temperature conditions.

(The IC is recommended that junctions are designed below 70% to 80% of Absolute Maximum Rating.)

14. Set the values of the capacitor between the VPUMP and GND pins so that the voltage on the VPUMP (Pin 17) will not transiently exceed 43 V in the transition from motor standby to motor start.

15. This IC employs a PWM drive method that switches the high-current output of the output transistor. Therefore, the IC is apt to generate noise that may cause the IC to malfunction or have fatal damage. To prevent these problems, the power supply must be stable enough. Therefore, the capacitance between the S5VOUT and GND pins must be a minimum of 0.1 μF and the one between the VM and GND pins must be a minimum of 47 μF and as close as possible to the IC so that PWM noise will not cause the IC to malfunction or have fatal damage.

16. A high current flows into the IC. Therefore, the common impedance of the PCB pattern cannot be ignored. Take the following points into consideration and design the PCB pattern of the motor.

A high current flows into the line between the VM1 (Pin 16) and VM2 (Pin 1) pins. Therefore, noise is generated with ease at the time of switching due to the inductance (L) of the line, which may result in the malfunctioning or destruction of the IC (see the circuit diagram 1). As shown in the circuit diagram 2, the escape way of the noise is secured by connecting a capacitor to the connector close to the VM pin of the IC. This makes it possible to suppress the direct VM pin voltage of the IC. Make the settings as shown in the circuit diagram 2 as much as possible.

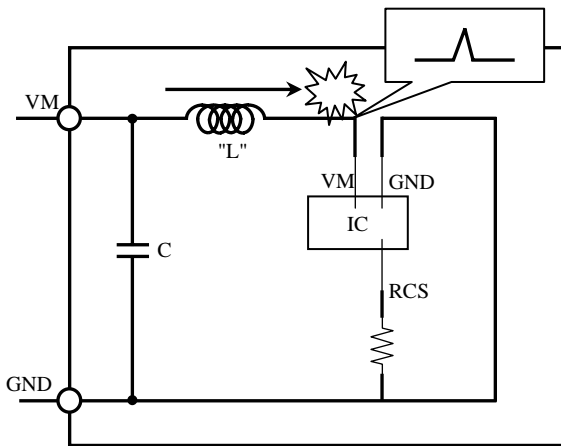


Diagram 1. Unrecommended pattern

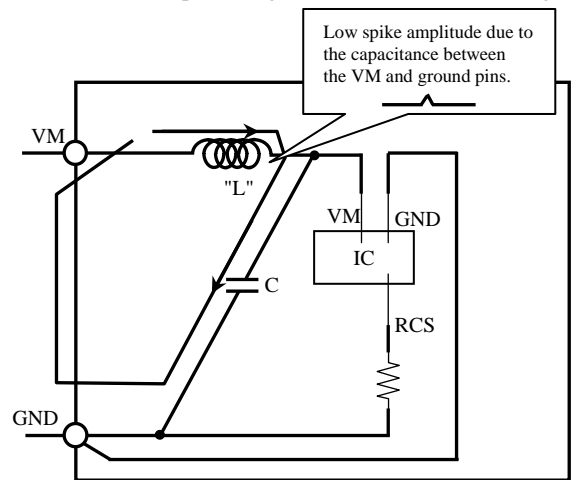
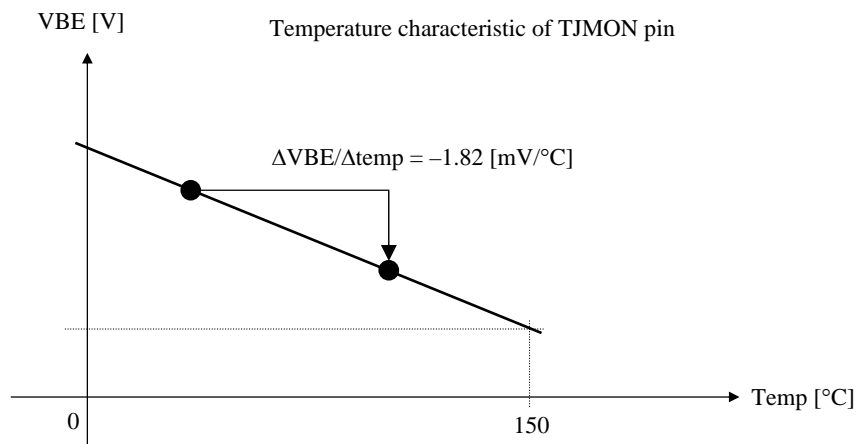


Diagram 2. Recommended pattern

17. In the case of measuring the chip temperature of the IC, measure the voltage of TJMON (Pin 34) and presume chip temperature from following data. Use the following data as reference data. Before applying the IC to a product, conduct a sufficient reliability test of the IC along with the evaluation of the product with the IC incorporated.



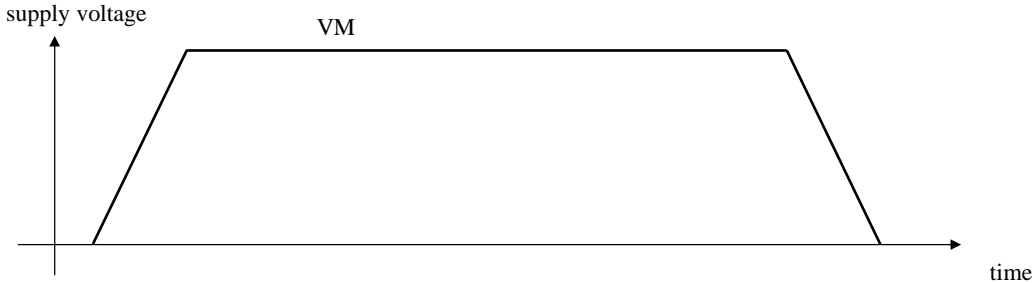
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■ Usage Notes (continued)

18. Power Supply Sequence

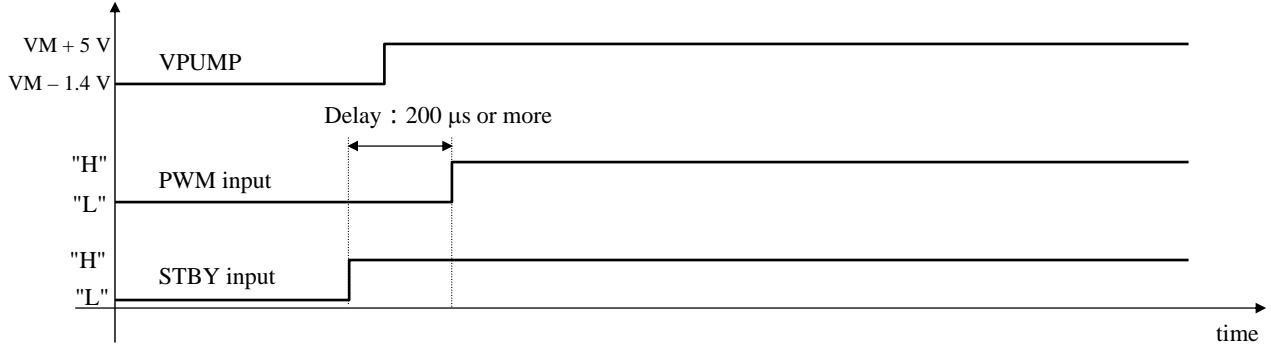
Rise/Fall slew rate are designed, V_M : below $0.1V/\mu s$.



19. Charge pump circuit

The charge pump circuit has stopped when the Low signal is input to STBY (Pin 28).

The start time is necessary until the charge pump circuit begins operating. Please take the wait time of $200 \mu s$ or more until the motor starts rotating after making IC active.



20. PWM operation

When Free Run Mode and Forward/Reverse Mode is repeated in PWM operation, the backflow current flows from GND toward VM in Free Run Mode. Please add external capacity so as not to exceed the absolute maximum rating of VM.

Also, when Free Run Mode and Forward/Reverse Mode is repeated in PWM operation, the duty of the output is extremely different from the duty of the input.

21. Thermal protection circuit

The operation point and hysteresis of the thermal protection circuit of the IC have about $\pm 10^\circ C$ of variation.

Also, the protection circuit is incorporated for the purpose of securing safety if the IC malfunctions. Therefore design a protection circuit so that a protection circuit will not operate under a normal operating condition.

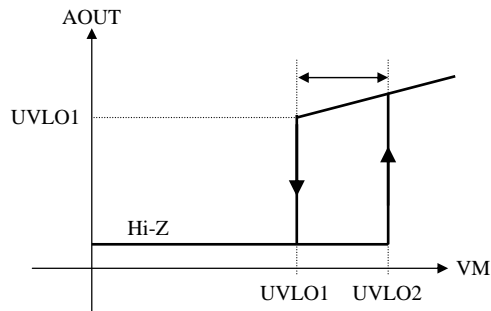
22. Low voltage detection circuit

The threshold of low voltage detection circuit of the IC is below,

Detection voltage (UVLO1) : Min = 7.1 V

Release voltage (UVLO2) : Max = 9.5 V

In case of less than the detection voltage, the power transistor of the motor output pins (AOUT1, AOUT2) on the flow-in side and another power transistor on the flow-out side turn off.



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■ Usage Notes (continued)

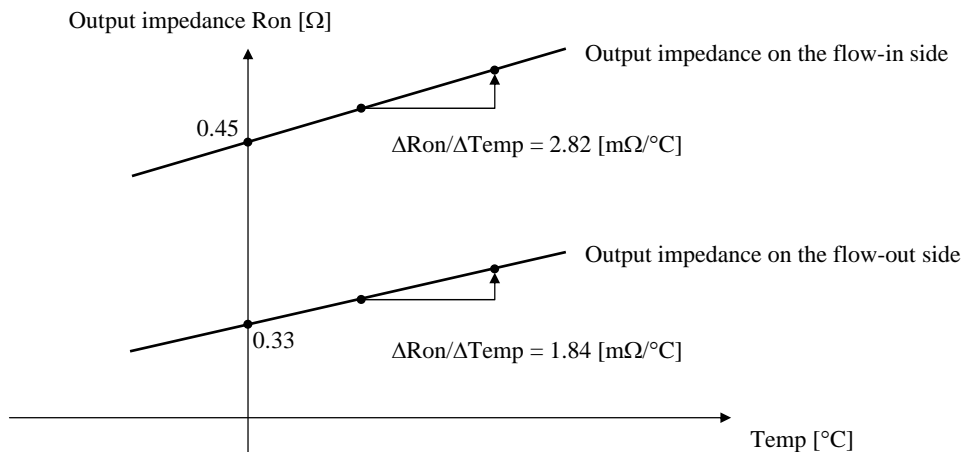
23. Operation within Supply Voltage Range

About Parameters from No.9 to No.28 in Electrical Characteristics, It is possible to gain characteristics described in Electrical Characteristics if operating within Supply Voltage Range (10 V to 35 V).

24. Temperature dependence of output impedance of motor drive output pins

Output impedance of motor drive output pins (Pin 3, 14) have temperature dependence below.

The characteristics below are reference values derived from the design of the IC and are not guaranteed by inspection. Conduct a sufficient reliability test of the IC along with the evaluation of the product with the IC incorporated.



25. No connected pins

When no connected pins (Pin 2, 4, 6, 13, 15, 20, 33) are connected to the GND pin, adjacent pin short or reverse insertion may cause destruction and smoke generation. Therefore, design the PCB pattern so that the above no connected pins are opened on the PCB pattern. There is no problem that no connected pins (Pin5, 10, 11, 12, 21) except for the above-mentioned pins are connected to the GND pin.

26. AOUT1 and AOUT2 pins after operation of the protection circuit of the IC

This IC has built-in thermal protection circuit, low voltage detection circuit and over current detection circuit.

AOUT1 and AOUT2 pins operate as below after each protection circuit operates,

Thermal protection circuit : In operating, the power transistor of AOUT1 and AOUT2 pins on the flow-in side and another power transistor on the flow-out side turn off. If the temperature of the IC lowers above thermal protection hysteresis width, AOUT1 and AOUT2 pins recover in normal operation automatically.

Low voltage detection circuit : In operating, the power transistor of AOUT1 and AOUT2 pins on the flow-in side and another power transistor on the flow-out side turn off. If VM pin voltage exceeds protection release voltage, AOUT1 and AOUT2 pins recover in normal operation automatically.

Over current detection circuit : In operating, the power transistor of AOUT1 and AOUT2 pins on the flow-in side and another power transistor on the flow-out side turn off, and keep this status latched. If over current detection circuit operates, reset the circuit by inputting low voltage to STBY pin or setting VM pin voltage to less than protection operating voltage.

27. Peak current detection and over current detection

Peak current detection values and over current detection values are obtained by following formula.

$$I_{peak1} = 0.1 \times VREFA / RCS[A]$$

$$I_{peak2} = 0.2 \times VREFB / RCS[A]$$

I_{peak1} : Peak current detection value

I_{peak2} : Over current detection value

VREFA : VREFA pin applied voltage

VREFB : VREFB pin applied voltage

RCS : RCSA1 / resistive connection between RCSA2 and GND pins

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PACKAGE STANDARDS

Package Code

HSOP034-P-0300A

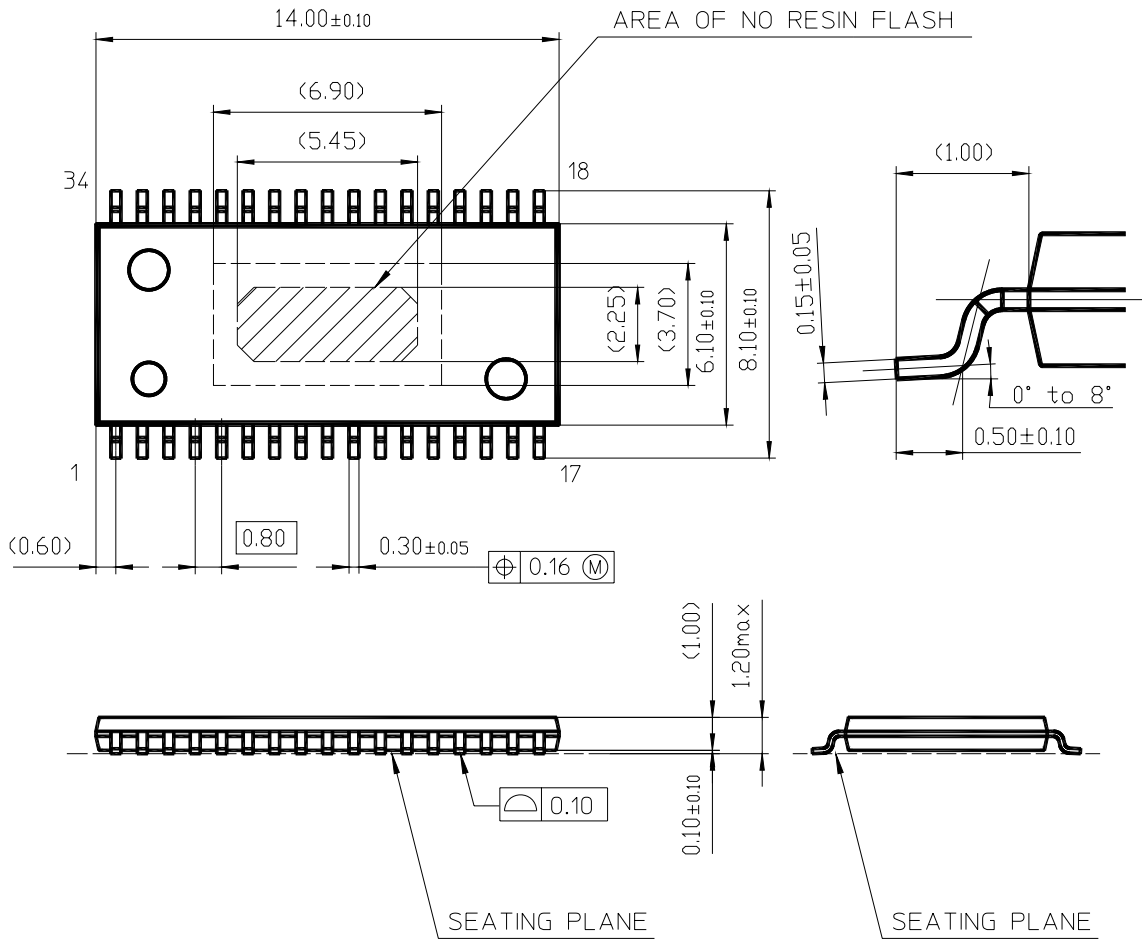
Semiconductor Company
Matsushita Electric Industrial Co., Ltd.

Established by	Applied by	Checked by	Prepared by
K.Komichi	H.Yoshida	M.Okajima	M.Itoh

	PACKAGE STANDARDS	
	HSOP034-P-0300A	
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1. Outline Drawing

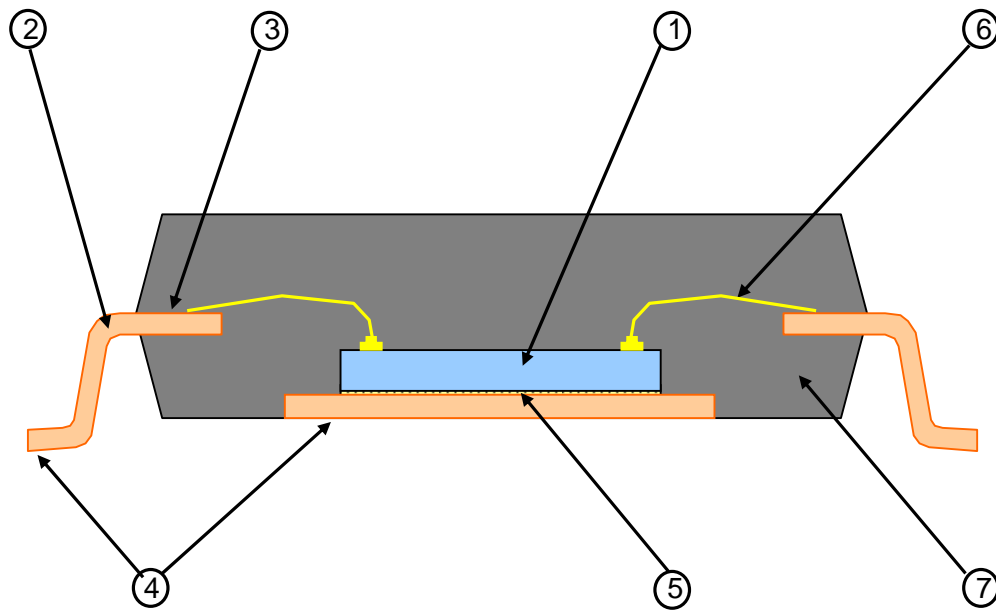
Unit:mm



Body Material	: Epoxy Resin
Lead Material	: Cu Alloy
Lead Finish Method	: Pd Plating

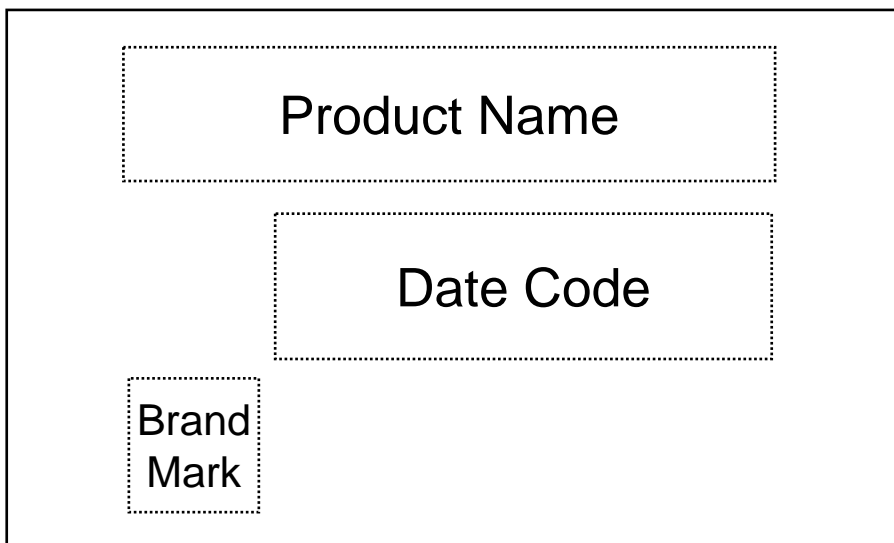
2. Package Structure (Technical Report : Reference Value)

Chip Material		Si	①
Leadframe material		Cu alloy	②
Inner lead surface		Pd plating	③
Outer lead surface		Pd plating	④
Chip mount	Method	Resin adhesive method	⑤
	Material	Adhesive material	
Wirebond	Method	Thermo-compression bonding	⑥
	Material	Au	
Molding	Method	Transfer molding	⑦
	Material	Epoxy resin	
Mass		250 mg	

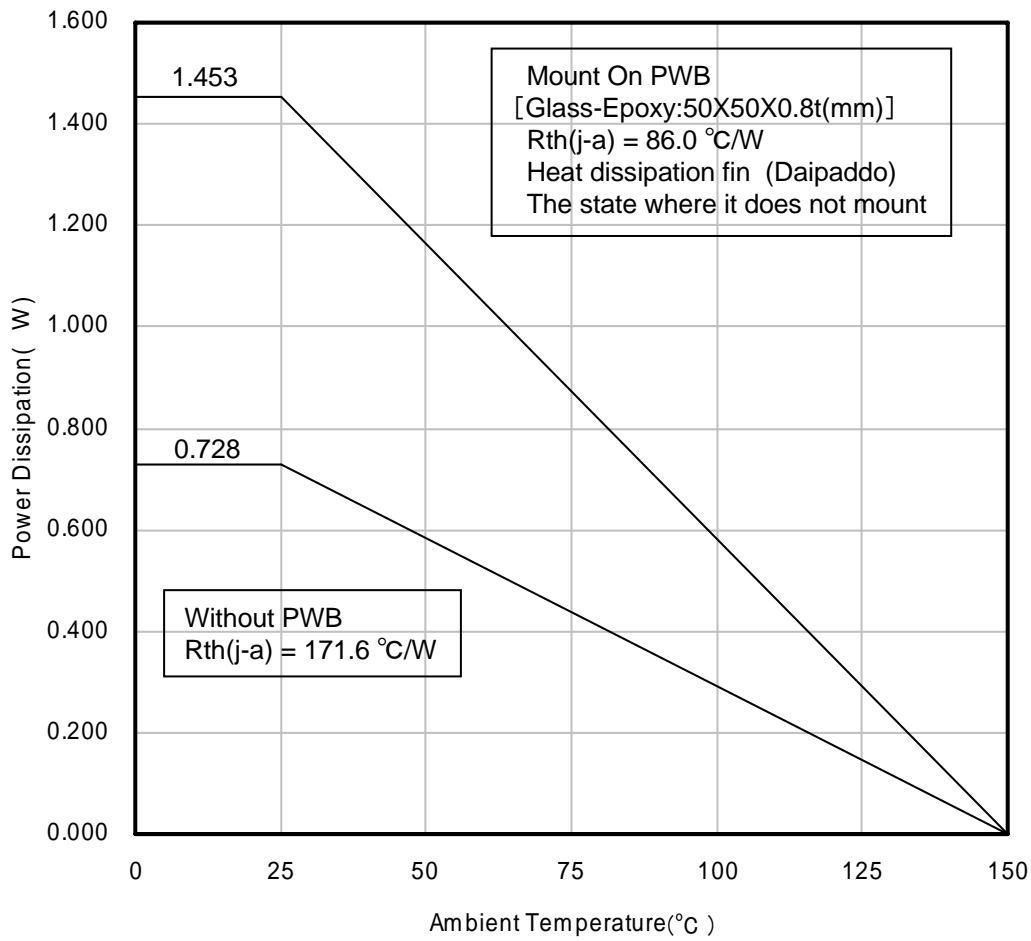


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3. Mark Drawing



4. Power Dissipation (Technical Report)



5. Power Dissipation (Supplementary Explanation)

[Experiment environment]

Power Dissipation (Technical Report) is a result in the experiment environment of SEMI standard conformity. (Ambient air temperature (Ta) is 25 degrees C)

[Supplementary information of PWB to be used for measurement]

The supplement of PWB information for Power Dissipation data (Technical Report) are shown below.

Indication	Total Layer	Resin Material
Glass-Epoxy	1-layer	FR-4
4-layer	4-layer	FR-4

[Notes about Power Dissipation (Thermal Resistance)]

Power Dissipation values (Thermal Resistance) depend on the conditions of the surroundings, such as specification of PWB and a mounting condition , and a ambient temperature. (Power Dissipation (Thermal Resistance) is not a fixed value.)

The Power Dissipation value (Technical Report) is the experiment result in specific conditions (evaluation environment of SEMI standard conformity) ,and keep in mind that Power Dissipation values (Thermal resistance) depend on circumference conditions and also change.

[Definition of each temperature and thermal resistance]

Ta : Ambient air temperature

The temperature of the air is defined at the position where the convection, radiation, etc. don't affect the temperature value, and it's separated from the heating elements.

Tc : It's the temperature near the center of a package surface. The package surface is defined at the opposite side if the PWB.

Tj : Semiconductor element surface temperature (Junction temperature.)

Rth(j-c) : The thermal resistance (difference of temperature of per 1 Watts) between a semiconductor element junction part and the package surface

Rth(c-a) : The thermal resistance (difference of temperature of per 1 Watts) between the package surface and the ambient air

Rth(j-a) : The thermal resistance (difference of temperature of per 1 Watts) between a semiconductor element junction part and the ambient air

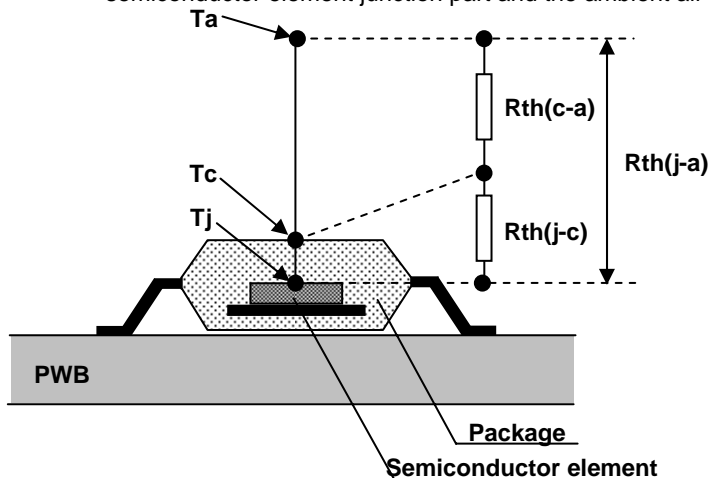


Fig1. Definition image

[Definition formula]

$$T_j = \{R_{th}(j-c) + R_{th}(c-a)\} \times P + T_a$$

$$= R_{th}(j-a) \times P + T_a$$

$$R_{th}(j-c) = \frac{T_j - T_c}{P} \quad (\text{ /W})$$

$$R_{th}(c-a) = \frac{T_c - T_a}{P} \quad (\text{ /W})$$

$$R_{th}(j-a) = \frac{T_j - T_a}{P} \quad (\text{ /W})$$

$$= R_{th}(j-c) + R_{th}(c-a)$$

P:power(W)